

Change in Lead Frame Material

< Affected products: DIP package products of Discrete Division produced at Oita Operations >

Date: June 26, 2015
Toshiba Corporation
Semiconductor & Storage
Products Company

Description of Change/ Product to be Affected

■ Reason of change

As the current lead frame supplier, Panasonic, will discontinue the lead frame business, it has become necessary to change the supplier.

- Description of changes
- Change in lead frame supplier/manufacturing site and plating specification for DIP package products of Discrete Division produced at Oita Operations

Change item	From	То			
Lead frame supplier	Panasonic	Company A			
Plating specification	SnAg-PPF	Pd-PPF			

 $\mathbf{\mathscr{R}PPF} = \mathbf{\underline{P}}$ re $\mathbf{\underline{P}}$ lated $\mathbf{\underline{F}}$ rame, which is a type of lead frame whose entire surface is plated at a time.

■ Product to be affected

Category	Part number to be affected
Standard logic CMOS	See List of affected products



♦ Changes in 5M1E

5M1E	From	То				
Man	No change					
Machine	No c	change				
Measurement	No c	hange				
Method	No c	hange				
Material	No change in quality/property of materials Including lead frame					
Lead frame supplier	Panasonic	Company A				
Plating specification	SnAg-PPF Au wire Ag plating SnAg plating SnAg plating Mold resin Lead frame (Cu)	Pd-PPF Au wire Chip Ni/Pd/Au plating Mold resin Lead frame(Cu)				
Environment	No change					

Material (quality/properties) and shape of lead frame will be unchanged.

The supplier to be applied has track record in manufacturing of lead frames for SOP packages with Pd plating

◆ FMEA for Risk Analysis

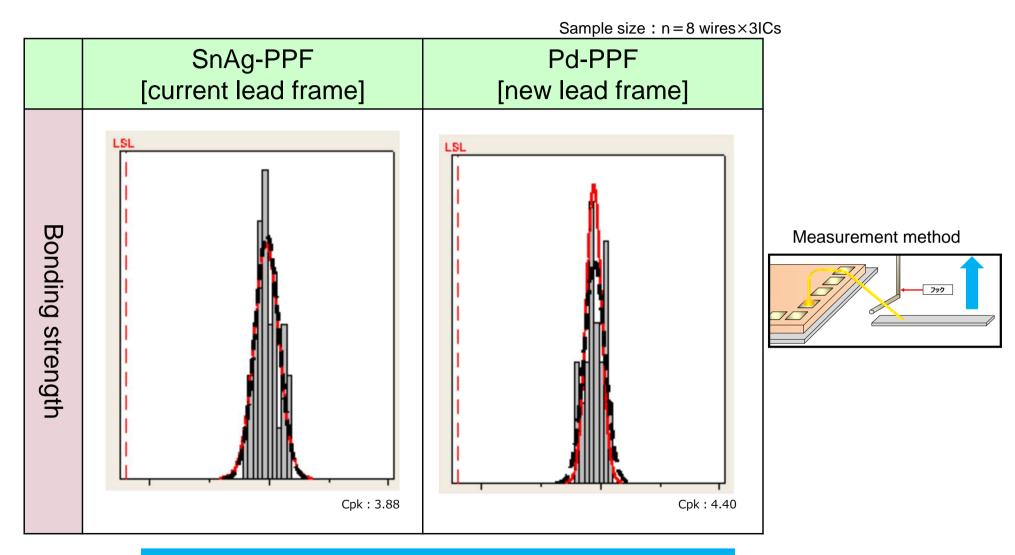
RPN is calculated based on scores of occurrence, severity and detection.

Items whose RPN is 105 or more have been subjected to unit evaluation.

Change point/ novelty	Process	Failure mode	220	Failure effect	SEV	Detection method	DET	RPN	Actions taken
	Wire bonding		5	Electrical/DC failure	7	Discovered inside Toshiba (by IQC)	3	105	Check of bondability on inner lead side
Change in lead frame supplier	Wire bonding	Poorly bonded wire on inner lead side	5	Electrical/DC failure	7	Discovered inside Toshiba (by outgoing inspection/special inspection)	5	175	Reliability test (TCT,PCT,THB,HTS)
	-	Problem in mounting	5	Defect in mounted appearance/dime nsions	7	Discovered at customer's site (by incoming/outgoing inspections)	7	245	Check of solderability
	Wire bonding		5	Electrical/DC failure	7	Discovered inside Toshiba (by IQC)	3	105	Check of bondability on inner lead side
Change in plating specification	Wire bonding	Poorly bonded wire on inner lead side	5	Electrical/DC failure	7	Discovered inside Toshiba (by outgoing inspection/special inspection)	5	175	Reliability test (TCT,PCT,THB,HTS)
	Lead trim & forming	Defect in trimmed/formed dimensions	10	Defect in mounted appearance/dime nsions	7	Discovered inside Toshiba (by IQC)	3	210	Check of bending width
	-	Problem in mounting	5	Defect in mounted appearance/dime nsions	7	Discovered at customer's site (by incoming/outgoing inspections)	7	245	Check of solderability



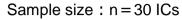
-Evaluation Data of Bondability on Inner Lead Side at Wire Bonding Process

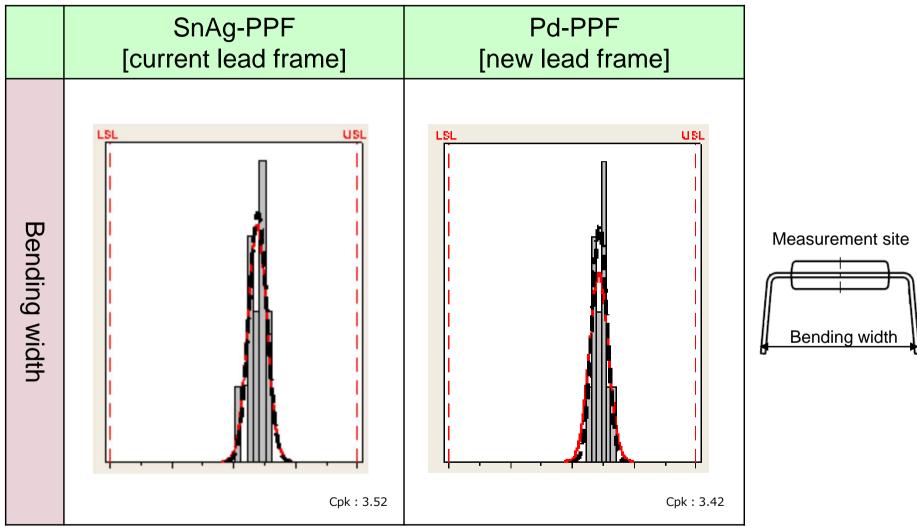


No problem without significant difference from the current lead frame



- Evaluation Data of Bending Width at Lead Trim & Forming Process





No problem without significant difference from the current lead frame



- Reliability Test Result

Test item	Test condition	Sample size	Read point Test result (reject/gross)		
Temperature cycle	est -65°C~150°C 30pcs×3 leadframe		300 cycles		
(TCT)			0 /30pcs×3 leadframe lots		
Pressure cooker test (PCT)	Ta=127°C, RH=100% 0.25MPa(non-condensing)	30pcs×3 leadframe	120 hours		
		lots	0 /30pcs×3 leadframe lots		
Temperature	Ta=85°C, RH=85% Power supply voltage= Operation Max		1000 hours		
Humidity Bias test (THB)		30pcs×3 leadframe lots	0/30pcs×3 leadframe lots		
High temperature	To 450°C	30pcs×3 leadframe	1000 hours		
storage (HTS)	Ta=150°C	lots	0/30pcs×3 leadframe lots		

^{*}The following pre-treatment was performed: solder dipping at 26degC for 10sec

No failure occurred.



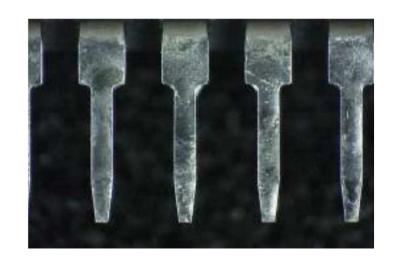
- Solderability Test Data

Test item	Sample size	Test result (reject/gross)
Solderability	12pcs	0/12pcs

SnAg-PPF [current lead frame]

Pd-PPF [new lead frame]





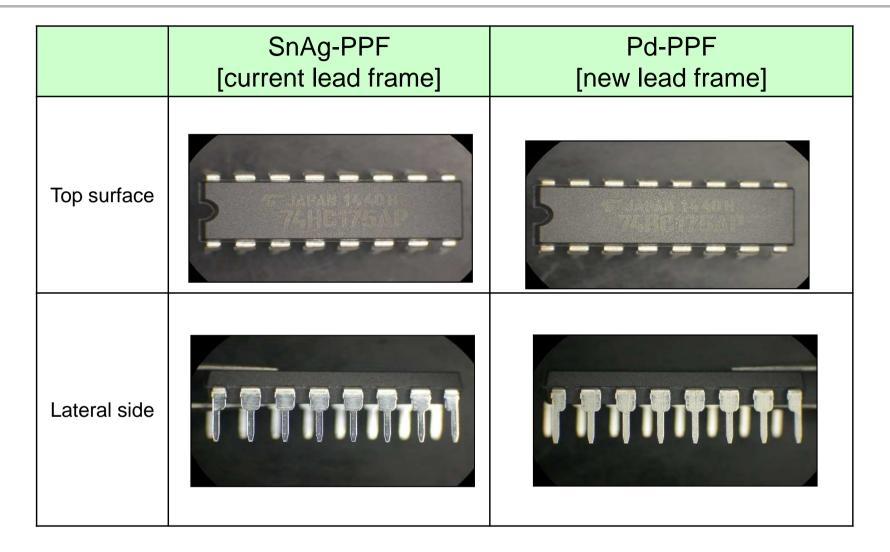
- Electrical Characteristics Comparison

DC characteristic		Measurement -		Spec (Ta=25℃)			Ave	rage	Cpk			
		Symbol	conditions	Min	Std	Max	Unit	Current frame	New frame	Current frame	New frame	判定
Input voltage	"H" level	VIH	VCC=4.5V	3.15	-	-	V	OK	ОК	-	-	ОК
	"L" level	VIL	VCC=4.5V	-	-	1.35	V	OK	ОК	-	-	OK
Output current	"H" level	IOH	VIN=VCCorGND VOH=4.18V VCC=4.5V	-	-	-4	mA	-7.205	-7.185	8.96	8.75	OK
	"L" level		VIN=VCCorGND VOL=0.26V VCC=4.5V	4	-	-	mA	6.915	6.976	4.61	4.42	OK
		IIH	VIN=VCC VCC=6V	-0.1	-	0.1	μΑ	0.005	0.005	23.73	21.28	ОК
Input curr	Current	IIL	VIN=GND VCC=6V	-0.1	-	0.1	μA	-0.012	-0.012	6.75	8.44	OK
Static consumption current		ICC	VIN=VCCorGND VCC=6V	-	-	4	μA	0.004	0.004	***	***	OK

No problem in process capabilities without significant difference from the current lead frame

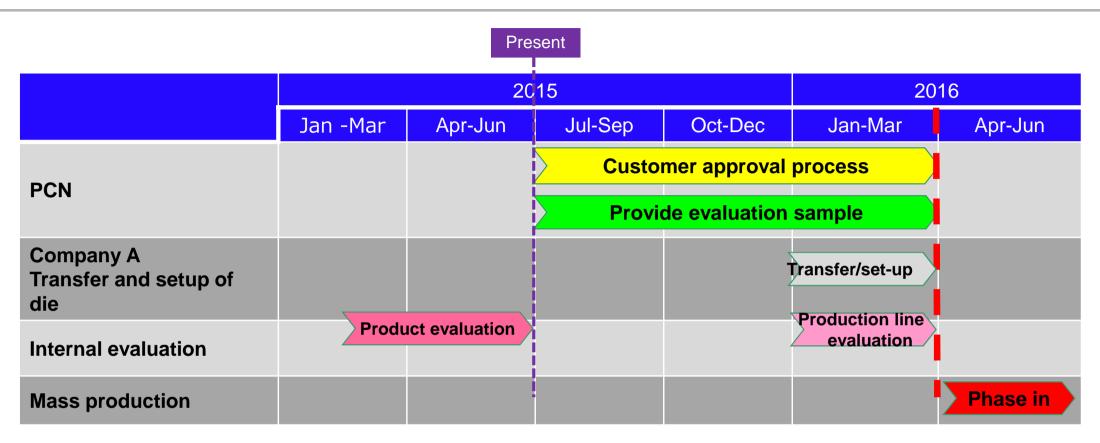


- Package Appearance Comparison



No problem in marking visibility without significant difference from the current package Slight difference in gloss of outer leads is due to difference in plating composition.

♦ Changeover Schedule





◆ Conclusion

< Request >

Toshiba has confirmed through the evaluations mentioned in this document that this lead frame change will cause no problem.

Therefore, you are kindly requested to internally review and consider approval for this change.

If you have requests for the relevant document/data or any questions, please inform our Sales representatives nearest you.

We would appreciate your understanding and cooperation.



TOSHIBA

Leading Innovation >>>